Renesas Electronics America Inc - R5F10Y16DSP#50 Datasheet

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	20MHz
Connectivity	CSI, I²C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	6
Program Memory Size	2KB (2K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 5.5V
Data Converters	A/D 4x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	10-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	10-LSSOP
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f10y16dsp-50

○ ROM, RAM capacities

Flash ROM	RAM	10 pins	16 pins
4 KB	512 B	–	R5F10Y47ASP Note 2
2 KB	256 B	R5F10Y16ASP	R5F10Y46ASP Note 2
1 KB	128 B	R5F10Y14ASP	R5F10Y44ASP Note 2

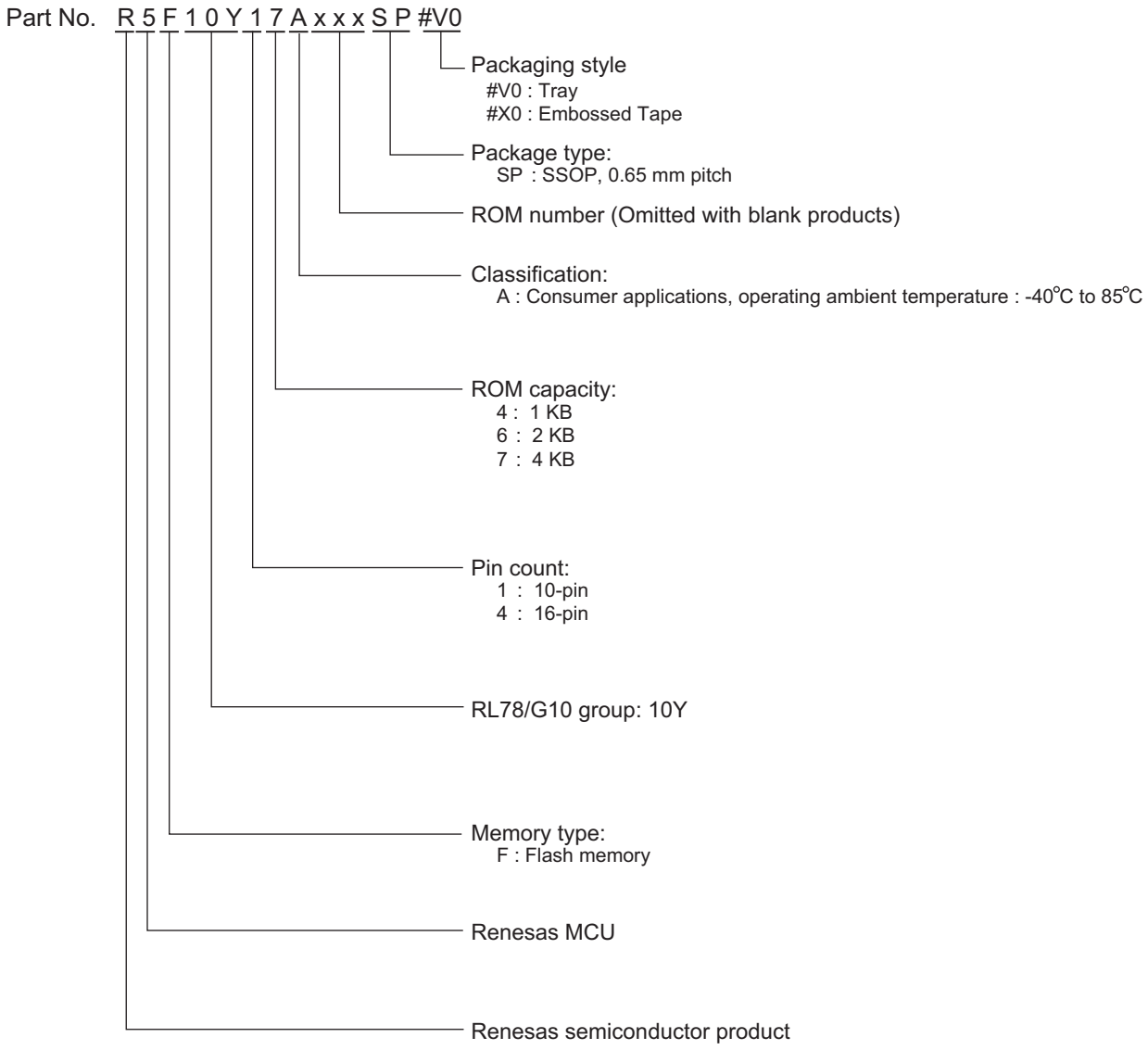
Notes 1. 16-pin products only

2. Under development

Remark The functions mounted depend on the product. See **1.6 Outline of Functions**.

1.2 List of Part Number

Figure 1-1. Classification of Part Number



Pin count	Package	Part Number
10 pins	10-pin plastic LSSOP (4.4 × 3.6 mm, 0.65mmpitch)	R5F10Y16ASP#V0, R5F10Y16ASP#X0
		R5F10Y14ASP#V0, R5F10Y14ASP#X0
16 pins	16-pin plastic SSOP (4.4 × 5.0 mm, 0.65mmpitch)	R5F10Y47ASP Note
		R5F10Y46ASP Note
		R5F10Y44ASP Note

Note Under development

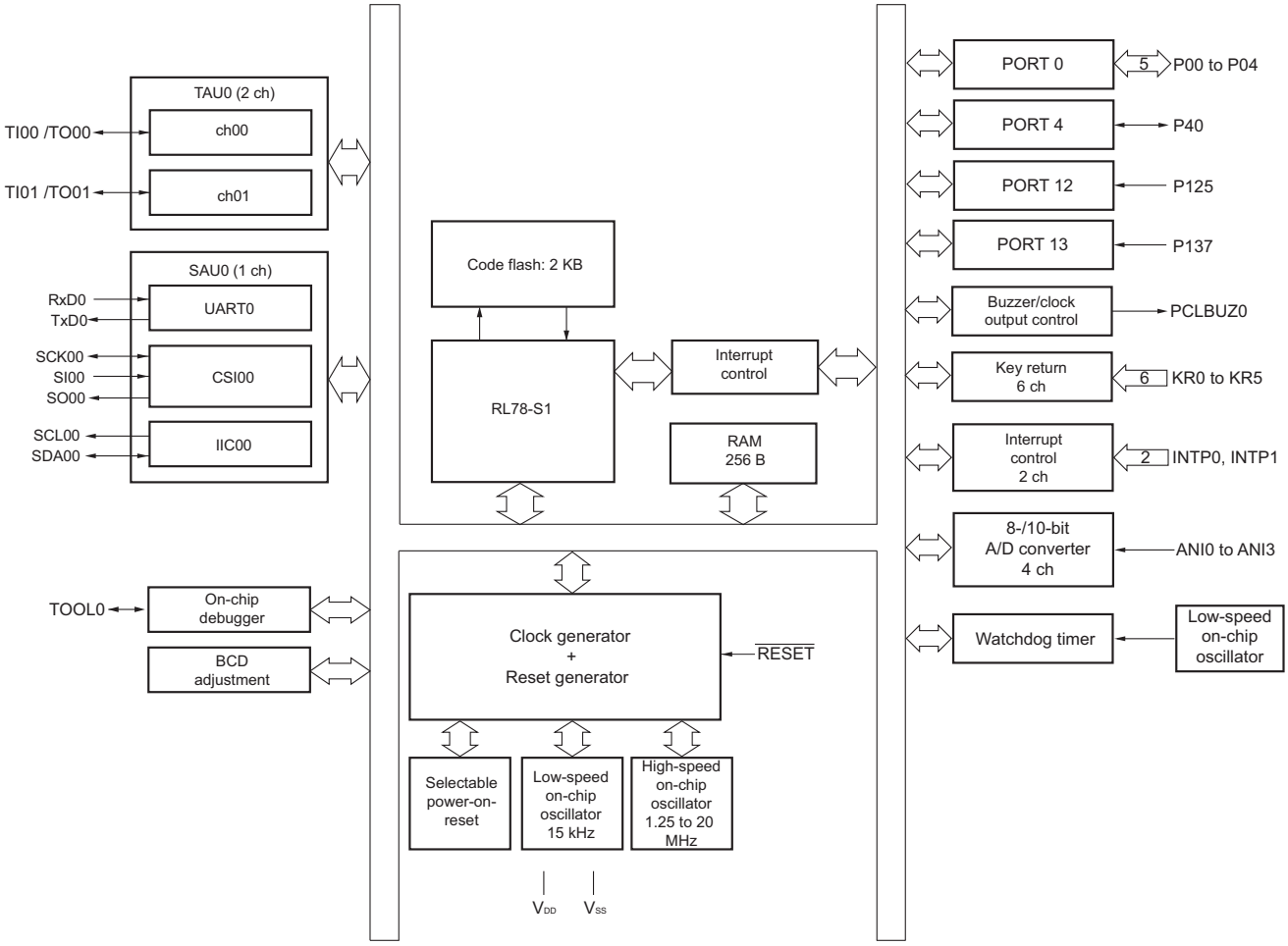
Caution The part number represents the number at the time of publication.
Be sure to review the latest part number through the target product page in the Renesas Electronics Corp.website.

1.4 Pin Identification

ANI0 to ANI6 : Analog Input
INTP0 to INTP3 : External Interrupt Input
KR0 to KR5 : Key Return
P00 to P07 : Port 0
P40, P41 : Port 4
P121, P122, P125 : Port 12
P137 : Port 13
PCLBUZ0 : Programmable Clock Output/ Buzzer Output
EXCLK : External Clock Input
X1, X2 : Crystal Oscillator
IVCMP0 : Comparator Input
VCOUT0 : Comparator Output
IVREF0 : Comparator Reference Input
$\overline{\text{RESET}}$: Reset
RxD0 : Receive Data
SCK00, SCK01 : Serial Clock Input/Output
SCL00, SCLA0 : Serial Clock Output
SDA00, SDAA0 : Serial Data Input/Output
SI00, SI01 : Serial Data Input
SO00, SO01 : Serial Data Output
TI00 to TI03 : Timer Input
TO00 to TO03 : Timer Output
TOOL0 : Data Input/Output for Tool
TxD0 : Transmit Data
V_{DD} : Power Supply
V_{SS} : Ground

1.5 Block Diagram

1.5.1 10-pin products



1.6 Outline of Functions

This outline describes the function at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

Item		10-pin		16-pin		
		R5F10Y16ASP	R5F10Y14ASP	R5F10Y47ASP	R5F10Y46ASP	R5F10Y44ASP
Code flash memory		2 KB	1 KB	4 KB	2 KB	1 KB
RAM		256 B	128 B	512 B	256 B	128 B
Main system clock	High-speed system clock	—		X1, X2 (crystal/ceramic) oscillation, external main system clock input (EXCLK): 1 to 20 MHz: V_{DD} = 2.7 to 5.5 V 1 to 5 MHz: V_{DD} = 2.0 to 5.5 V		
	High-speed on-chip oscillator clock	• 1.25 to 20 MHz (V_{DD} = 2.7 to 5.5 V) • 1.25 to 5 MHz (V_{DD} = 2.0 to 5.5 V)				
Low-speed on-chip oscillator clock		15 kHz (TYP)				
General-purpose register		8-bit register × 8				
Minimum instruction execution time		0.05 μs (20 MHz operation)				
Instruction set		• Data transfer (8 bits) • Adder and subtractor/logical operation (8 bits) • Multiplication (8 bits × 8 bits) • Rotate, barrel shift, and bit manipulation (set, reset, test, and Boolean operation), etc.				
I/O port	Total	8		14		
	CMOS I/O	6 (N-ch open-drain output (V_{DD} tolerance): 2)		10 (N-ch open-drain output (V_{DD} tolerance): 4)		
	CMOS input	2		4		
Timer	16-bit timer	2 channels		4 channels		
	Watchdog timer	1 channel				
	12-bit interval timer	—		1 channel		
	Timer output	2 channels (PWM output: 1)		4 channels (PWM outputs: 3[Note 1])		
Clock output/buzzer output		1				
		2.44 kHz to 10 MHz: (Peripheral hardware clock: f_{MAIN} = 20 MHz operation)				
Comparator		—		1		
8-/10-bit resolution A/D converter		4 channels		8 channels		
Serial interface		[10-pin products] CSI: 1 channel/simplified I^2C: 1 channel/UART: 1 channel [16-pin products] CSI: 2 channels/simplified I^2C: 1 channel/UART: 1 channel				
	I^2C bus	—		1 channel		
Vectored interrupt sources	Internal	8		14		
	External	3		5		
Key interrupt		6				
Reset		• Reset by $\overline{\text{RESET}}$ pin • Internal reset by watchdog timer • Internal reset by selectable power-on-reset • Internal reset by illegal instruction execution [Note 2] • Internal reset by data retention lower limit voltage				
Selectable power-on-reset circuit		Detection voltage: 2.0 V/2.4 V/2.7 V/4.0 V				
On-chip debug function		Provided				
Power supply voltage		V_{DD} = 2.0 to 5.5 V				
Operating ambient temperature		T_A = - 40 to + 85 °C				

2.3 DC Characteristics

2.3.1 Pin characteristics

(T_A = –40 to +85°C, 2.0 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Output current, high[Note 1]	I_{OH1}	P00, P01, P02 to P04, P40	Per pin				-10.0[Note 2]	mA
		P40	Total[Note 3]	4.0 V ≤ V_{DD} ≤ 5.5 V			-10.0	mA
				2.7 V ≤ V_{DD} < 4.0 V			-2.0	mA
				2.0 V ≤ V_{DD} < 2.7 V			-1.5	mA
		P00, P01, P02 to P04	Total[Note 3]	4.0 V ≤ V_{DD} ≤ 5.5 V			-50.0	mA
				2.7 V ≤ V_{DD} < 4.0 V			-10.0	mA
				2.0 V ≤ V_{DD} < 2.7 V			-7.5	mA
		Total of all pins[Note 3]					-60.0	mA
Output current, low[Note 4]	I_{OL1}	P00 to P04, P40	Per pin				20.0[Note 2]	mA
		P40	Total[Note 3]	4.0 V ≤ V_{DD} ≤ 5.5 V			20.0	mA
				2.7 V ≤ V_{DD} < 4.0 V			3.0	mA
				2.0 V ≤ V_{DD} < 2.7 V			0.6	mA
		P00 to P04	Total[Note 3]	4.0 V ≤ V_{DD} ≤ 5.5 V			80.0	mA
				2.7 V ≤ V_{DD} < 4.0 V			12.0	mA
				2.0 V ≤ V_{DD} < 2.7 V			2.4	mA
		Total of all pins[Note 3]					100.0	mA
Input voltage, high	V_{IH1}				0.8 V_{DD}		V_{DD}	V
Input voltage, low	V_{IL1}				0		0.2 V_{DD}	V
Output voltage, high[Note 5]	V_{OH1}	4.0 V ≤ V_{DD} ≤ 5.5 V		I_{OH} = -10 mA	V_{DD}-1.5			V
				I_{OH} = -3.0 mA	V_{DD}-0.7			V
		2.7 V ≤ V_{DD} ≤ 5.5 V		I_{OH} = -2.0 mA	V_{DD}-0.6			V
		2.0 V ≤ V_{DD} ≤ 5.5 V		I_{OH} = -1.5 mA	V_{DD}-0.5			V
Output voltage, low[Note 6]	V_{OL1}	4.0 V ≤ V_{DD} ≤ 5.5 V		I_{OL} = 20 mA			1.3	V
				I_{OL} = 8.5 mA			0.7	V
		2.7 V ≤ V_{DD} ≤ 5.5 V		I_{OL} = 3.0 mA			0.6	V
				I_{OL} = 1.5 mA			0.4	V
		2.0 V ≤ V_{DD} ≤ 5.5 V		I_{OL} = 0.6 mA			0.4	V
Input leakage current, high	I_{LIH1}	V_I = V_{DD}					1	μA
Input leakage current,low	I_{LIL1}	V_I = V_{SS}					-1	μA
On-chip pull-up resistance	R_U	V_I = V_{SS}			10	20	100	kΩ

Notes 1. Value of current at which the device operation is guaranteed even if the current flows from the V_{DD} pin to an output pin.

2. Do not exceed the total current value.

3. This is the output current value under conditions where the duty factor ≤ 70%.
The output current value when the duty factor > 70% can be calculated with the following expression (when changing the duty factor to n%).

- Total output current of pins = (I_{OH} × 0.7)/(n × 0.01)
  <Example> Where n = 80 % and I_{OH} = - 10.0 mA
  Total output current of pins = (- 10.0 × 0.7)/(80 × 0.01) ≅ - 8.7 mA
- Total output current of pins = (I_{OL} × 0.7)/(n × 0.01)
  <Example> Where n = 80 % and I_{OL} = 10.0 mA
  Total output current of pins = (10.0 × 0.7)/(80 × 0.01) ≅ 8.7 mA

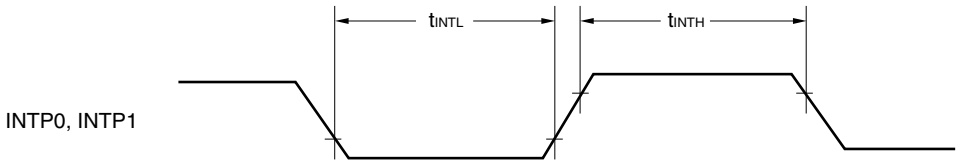
However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

4. Value of current at which the device operation is guaranteed even if the current flows from an output pin to the V_{SS} pin.
5. The value under the condition which satisfies the high-level output current (I_{OH1}).
6. The value under the condition which satisfies the low-level output current (I_{OL1}).

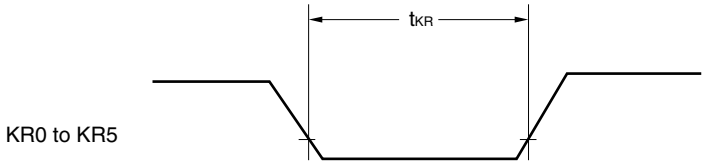
Cautions 1. P00 and P01 do not output high level in N-ch open-drain mode.
2. The maximum value of V_{IH} of P00 and P01 is V_{DD} even in N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port.

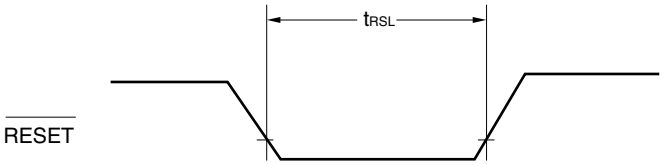
Interrupt Request Input Timing



Key Interrupt Input Timing



$\overline{\text{RESET}}$ Input Timing



2.5 Serial Communication Characteristics

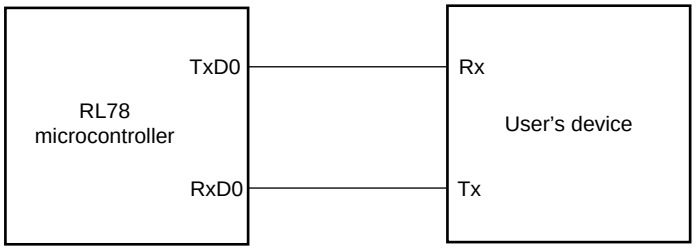
2.5.1 Serial array unit

(1) UART mode

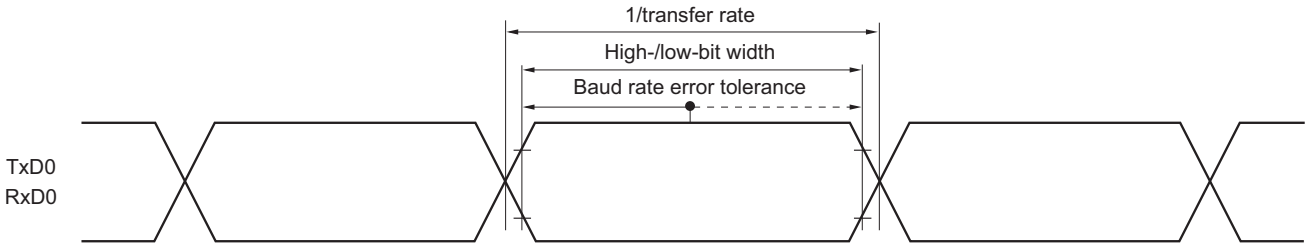
(T_A = −40 to +85°C, 2.0 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate					f_{MCK}/6	bps
		Theoretical value of the maximum transfer rate f_{CLK} = f_{MCK} = 20 MHz			3.3	Mbps

UART mode connection diagram



UART mode bit width (reference)



Remark f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00))

(2) CSI mode (master mode, SCKp... internal clock output)

(T_A = –40 to +85°C, 2.0 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
SCKp cycle time	t_{KCY1}	$t_{KCY1} \geq 4/f_{CLK}$	2.7 V ≤ V_{DD} ≤ 5.5 V	200			ns
			2.0 V ≤ V_{DD} ≤ 5.5 V	800			ns
SCKp high-/low-level width	t_{KH1}, t_{KL1}	2.7 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2-18			ns
		2.0 V ≤ V_{DD} ≤ 5.5 V		t_{KCY1}/2-50			ns
SIp setup time (to SCKp↑) Note 1	t_{SIK1}	2.7 V ≤ V_{DD} ≤ 5.5 V		47			ns
		2.0 V ≤ V_{DD} ≤ 5.5 V		110			ns
SIp hold time (from SCKp↑) Note 2	t_{KSI1}			19			ns
Delay time from SCKp↓ to SOp output Note 3	t_{KSO1}	C = 30 pF Note 4				25	ns

Notes 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

4. C is the load capacitance of the SCKp and SOp output lines.

Remarks 1. p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0)

2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00))

(3) CSI mode (slave mode, SCKp... external clock input)

(T_A = –40 to +85°C, 2.0 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
SCKp cycle time	t_{KCY2}	2.7 V ≤ V_{DD} ≤ 5.5 V	f_{MCK} = 20 MHz	8/f_{MCK}			ns
			f_{MCK} ≤ 10 MHz	6/f_{MCK}			ns
		2.0 V ≤ V_{DD} < 2.7 V		6/f_{MCK}			ns
SCKp high-/low-level width	t_{KH2}, t_{KL2}	2.0 V ≤ V_{DD} ≤ 5.5 V		t_{KCY2}/2			ns
SIp setup time (to SCKp↑)[Note 1]	t_{SIK2}	2.7 V ≤ V_{DD} ≤ 5.5 V		1/f_{MCK} + 20			ns
		2.0 V ≤ V_{DD} < 2.7 V		1/f_{MCK} + 30			ns
SIp hold time (from SCKp↑) [Note 2]	t_{KSI2}	2.0 V ≤ V_{DD} ≤ 5.5 V		1/f_{MCK} + 31			ns
Delay time from SCKp↓ to SOp output [Note 3]	t_{KSO2}	C = 30 pF [Note 4]	2.7 V ≤ V_{DD} ≤ 5.5 V			2/f_{MCK} + 50	ns
			2.0 V ≤ V_{DD} < 2.7 V			2/f_{MCK} + 110	ns

Notes 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

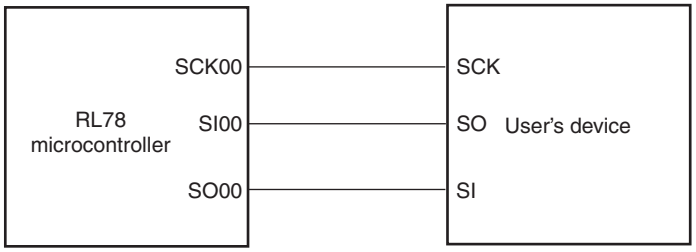
3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

4. C is the load capacitance of the SOp output lines.

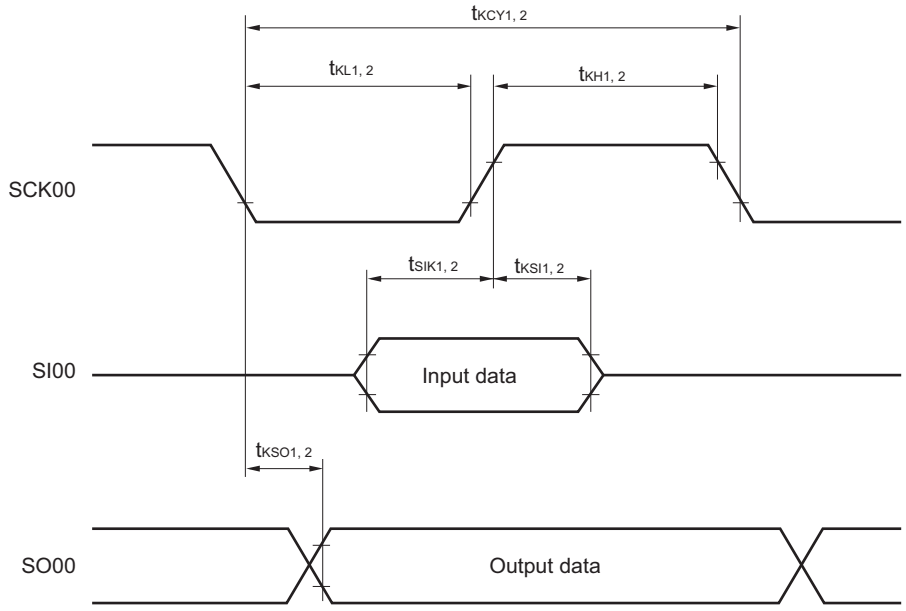
Remarks 1. p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0)

2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

CSI mode connection diagram



CSI mode serial transfer timing
(When DAP00 = 0 and CKP00 = 0, or DAP00 = 1 and CKP00 = 1.)



(4) Simplified I²C mode

(T_A = –40 to +85°C, 2.0 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
SCLr clock frequency	f_{SCL}	2.0 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ		400 Note 1	kHz
Hold time when SCLr = "L"	t_{LOW}	2.0 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	1150		ns
Hold time when SCLr = "H"	t_{HIGH}	2.0 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	1150		ns
Data setup time (reception)	$t_{SU:DAT}$	2.0 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	1/f_{MCK} + 145 Note 2		ns
Data hold time (transmission)	$t_{HD:DAT}$	2.0 V ≤ V_{DD} ≤ 5.5 V, C_b = 100 pF, R_b = 3 kΩ	0	355	ns

Notes 1. The value must also be equal to or less than f_{MCK}/4.

2. Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

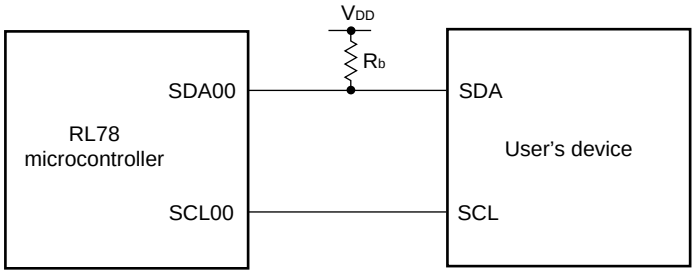
Caution Select the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin by using the port output mode register 0 (POM0).

Remarks 1. R_b [Ω]: Communication line (SDAr) pull-up resistance, C_b [F]: Communication line (SCLr, SDAr) load capacitance

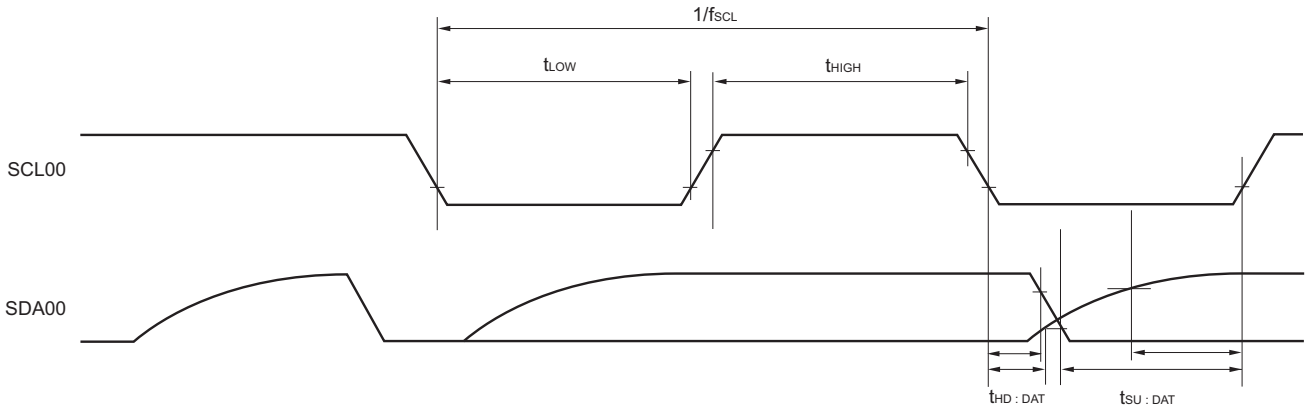
2. r: IIC number (r = 00)

3. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00))

Simplified I²C mode connection diagram



Simplified I²C mode serial transfer timing



2.6 Analog Characteristics

2.6.1 A/D converter characteristics

(Target ANI pin : ANI0 to ANI3)

(T_A = –40 to +85°C, 2.4 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	R_{ES}			8		10	bit
Overall error[Note 1]	AINL	10-bit resolution	V_{DD} = 5 V		±1.7	±3.1[Note 2]	LSB
			V_{DD} = 3 V		±2.3	±4.5[Note 2]	LSB
Conversion time	t_{CONV}	10-bit resolution	2.7 V ≤ V_{DD} ≤ 5.5 V	3.4		18.4	µs
			2.4 V ≤ V_{DD} ≤ 5.5 V	4.6		18.4	µs
Zero-scale error[Note 1]	E_{ZS}	10-bit resolution	V_{DD} = 5 V			±0.19[Note 2]	%FSR
			V_{DD} = 3 V			±0.39[Note 2]	%FSR
Full-scale error[Note 1]	E_{FS}	10-bit resolution	V_{DD} = 5 V			±0.29[Note 2]	%FSR
			V_{DD} = 3 V			±0.42[Note 2]	%FSR
Integral linearity error[Note 1]	ILE	10-bit resolution	V_{DD} = 5 V			±1.8[Note 2]	LSB
			V_{DD} = 3 V			±1.7[Note 2]	LSB
Differential linearity error[Note 1]	DLE	10-bit resolution	V_{DD} = 5 V			±1.4[Note 2]	LSB
			V_{DD} = 3 V			±1.5[Note 2]	LSB
Analog input voltage	V_{AIN}			0		V_{DD}	V

Notes 1. Excludes quantization error (±1/2 LSB).

2. This is the characteristic evaluation value plus or minus 3. These values are not used in the shipping inspection.

2.6.2 SPOR circuit characteristics

(T_A = –40 to +85°C, V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection supply voltage	V_{SPOR0}	Power supply rise time	4.08	4.28	4.45	V
		Power supply fall time	4.00	4.20	4.37	V
	V_{SPOR1}	Power supply rise time	2.76	2.90	3.02	V
		Power supply fall time	2.70	2.84	2.96	V
	V_{SPOR2}	Power supply rise time	2.44	2.57	2.68	V
		Power supply fall time	2.40	2.52	2.62	V
	V_{SPOR3}	Power supply rise time	2.05	2.16	2.25	V
		Power supply fall time	2.00	2.11	2.20	V
Minimum pulse width[Note]	T_{SPW}		300			µs

Note Time required for the reset operation by the SPOR when V_{DD} becomes under V_{SPDR}.

2.6.3 Power supply voltage rising slope characteristics

(T_A = –40 to +85°C, V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S_{VDD}				54	V/ms

2.6.4 Data retention power supply voltage characteristics

(T_A = –40 to +85°C, Vss = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention power supply voltage range	V_{DDDR}		1.9		5.5	V

Caution Data is retained until the power supply voltage becomes under the minimum value of the data retention power supply voltage range. Note that data in the RAM and RESF registers might not be cleared even if the power supply voltage becomes under the minimum value of the data retention power supply voltage range.

2.7 Flash Memory Programming Characteristics

(T_A = 0 to + 40°C, 4.5 V ≤ V_{DD} ≤ 5.5 V, V_{SS} = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Code flash memory rewritable times Notes 1, 2, 3	C_{erwr}	Retained for 20 years.	T_A = + 85°C	1000			Times

Notes 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

2. When using flash memory programmer.

3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

2.8 Dedicated Flash Memory Programmer Communication (UART)

(T_A = 0 to + 40°C, 4.5 V ≤ V_{DD} ≤ 5.5V, V_{SS} = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate				115,200		bps

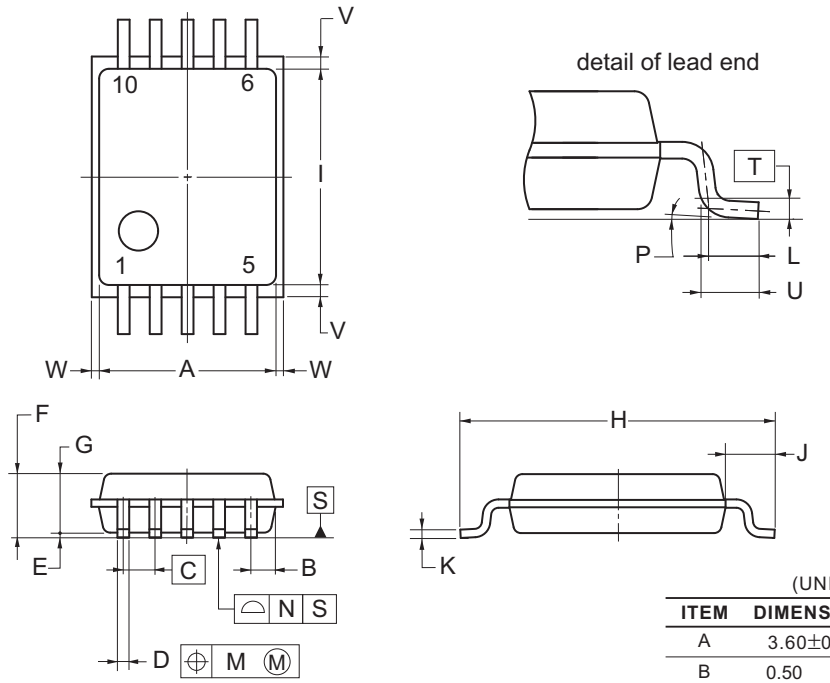
Remark The transfer rate during flash memory programming is fixed to 115,200 bps.

3. PACKAGE DRAWINGS

3.1 10-pin products

R5F10Y16ASP, R5F10Y14ASP

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LSSOP10-4.4x3.6-0.65	PLSP0010JA-A	P10MA-65-CAC-2	0.05



(UNIT:mm)

ITEM	DIMENSIONS
A	3.60±0.10
B	0.50
C	0.65 (T.P.)
D	0.24±0.08
E	0.10±0.05
F	1.45 MAX.
G	1.20±0.10
H	6.40±0.20
I	4.40±0.10
J	1.00±0.20
K	$0.17^{+0.08}_{-0.07}$
L	0.50
M	0.13
N	0.10
P	$3^{\circ}{}^{+5^{\circ}}_{-3^{\circ}}$
T	0.25 (T.P.)
U	0.60±0.15
V	0.25 MAX.
W	0.15 MAX.

NOTE
Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

Revision History	RL78/G10 Data Sheet

Rev.	Date	Description	
		Page	Summary
1.00	Apr 15, 2013	-	First Edition issued

Caution: This product uses SuperFlash® technology licensed from Silicon Storage Technology, Inc.

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